

Laser Scribing Patterning for the Production of Organometallic Halide Perovskite Solar Modules



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Motivation

What are the advantages of the organometallic halide perovskite?

1. Tunable dimensionality
2. Tunable optical and electronic property
3. Low-cost process-based solution process
4. High molar extinction efficient
5. Steep absorption onset and no optically detected deep states

However, most of high efficiencies have been achieved on laboratory scale area below 0.5 cm².

CSEM task is to upscale perovskite solar cell:

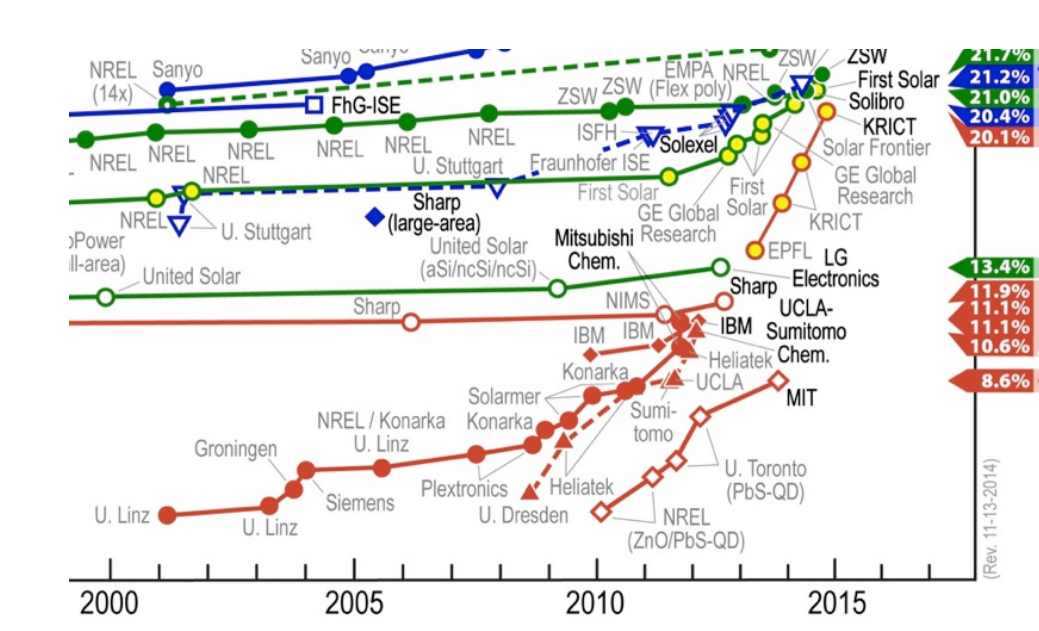
CSEM is focusing on optimizing perovskite layer via laser scribing for patterning, production-oriented processes such as wet coating, spin-coating or new innovative coating, with the final aim of transferring the high efficiency achieved in the labs to pre-production scale mini-modules.

Laser patterning

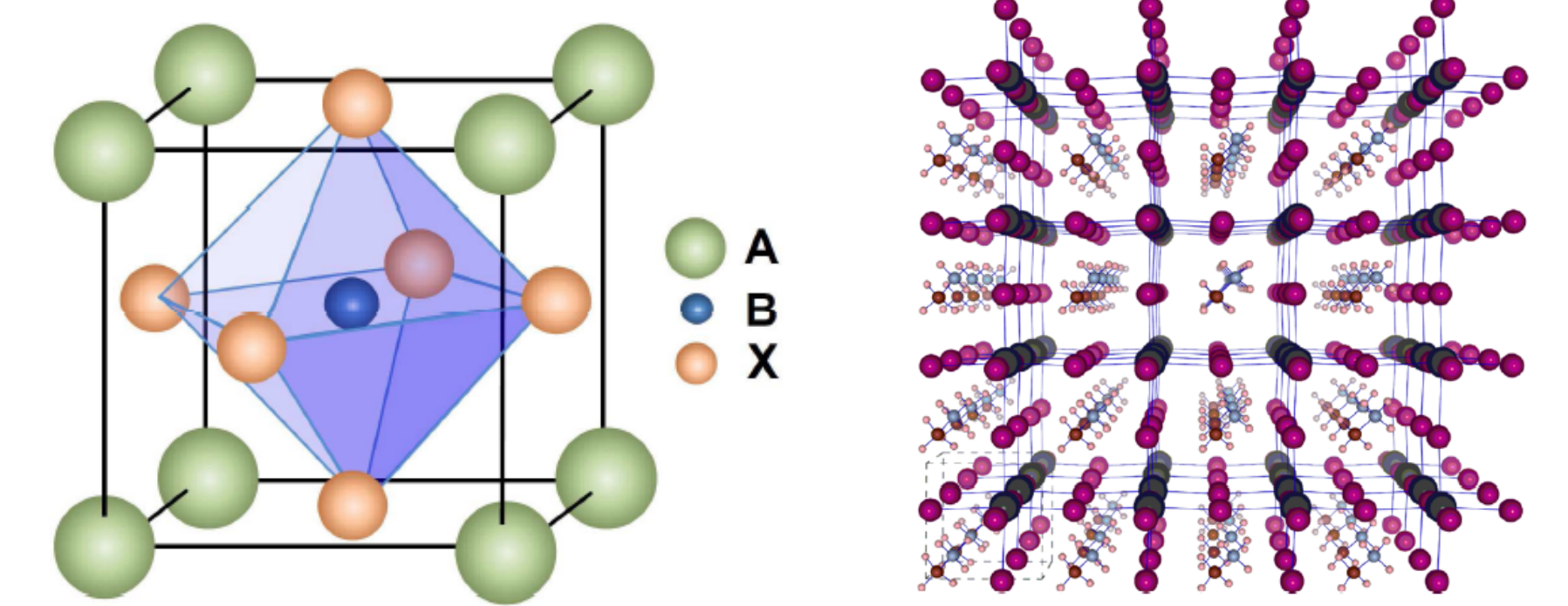
- W_d < 300 μm
- Precision tool (focus down to 20 μm)
- Non contact process (use of brittle materials in PV: silicon, glass, TCO)
- Fast positioning and process
- Selectivity

Production Process	Production Status			
	Thin film silicon	Cd Te	CIS/ CIGS	Flexibles
P1 Patterning	✓	✓	✓	✓
P2 Patterning	✓	✓	✓	✓
P3 Patterning	✓	✓	✓	✓
Laser Edge Isolation	✓	✓	✓	✓
Crystallization	✓	✓	✓	✓

Table 1 Laser processes for thin-film PV and status for industrial production.
H. BOOTH, J. Laser Micro. Nanoen. 2010, 5, 195-203.

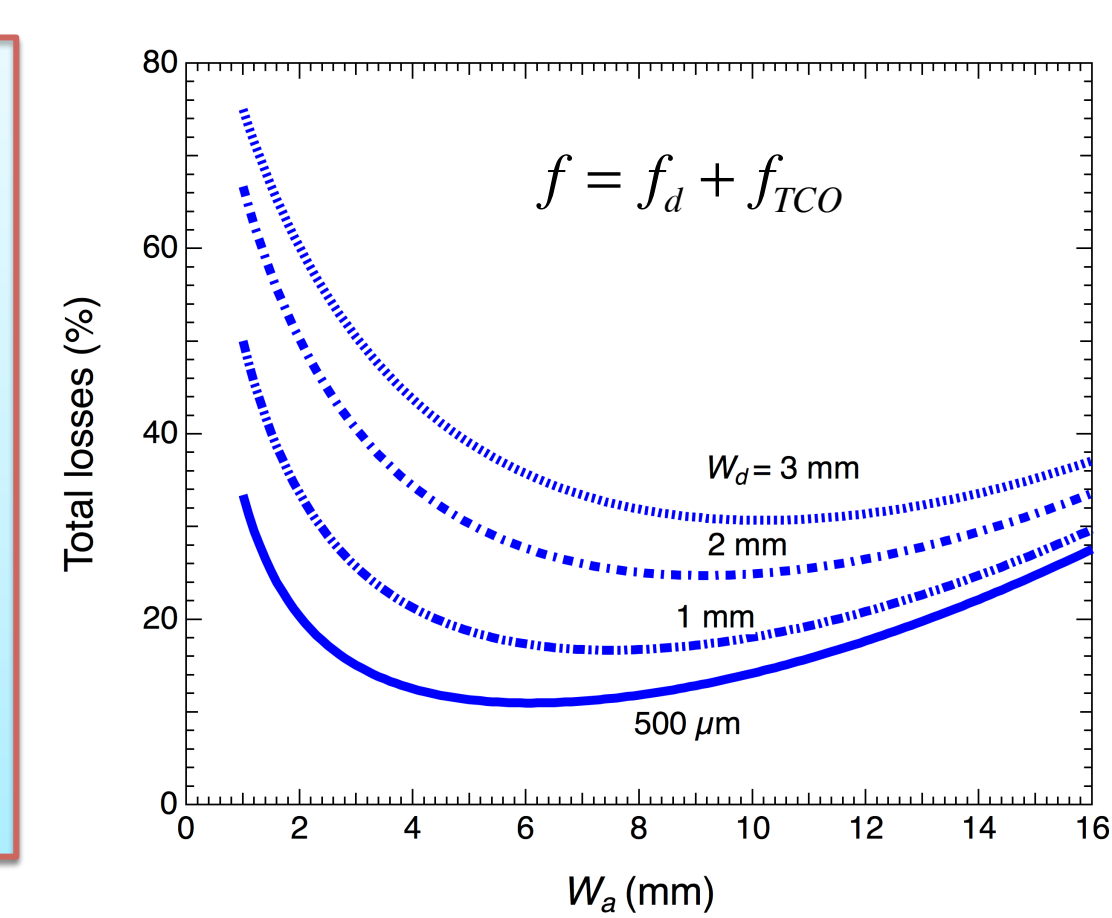
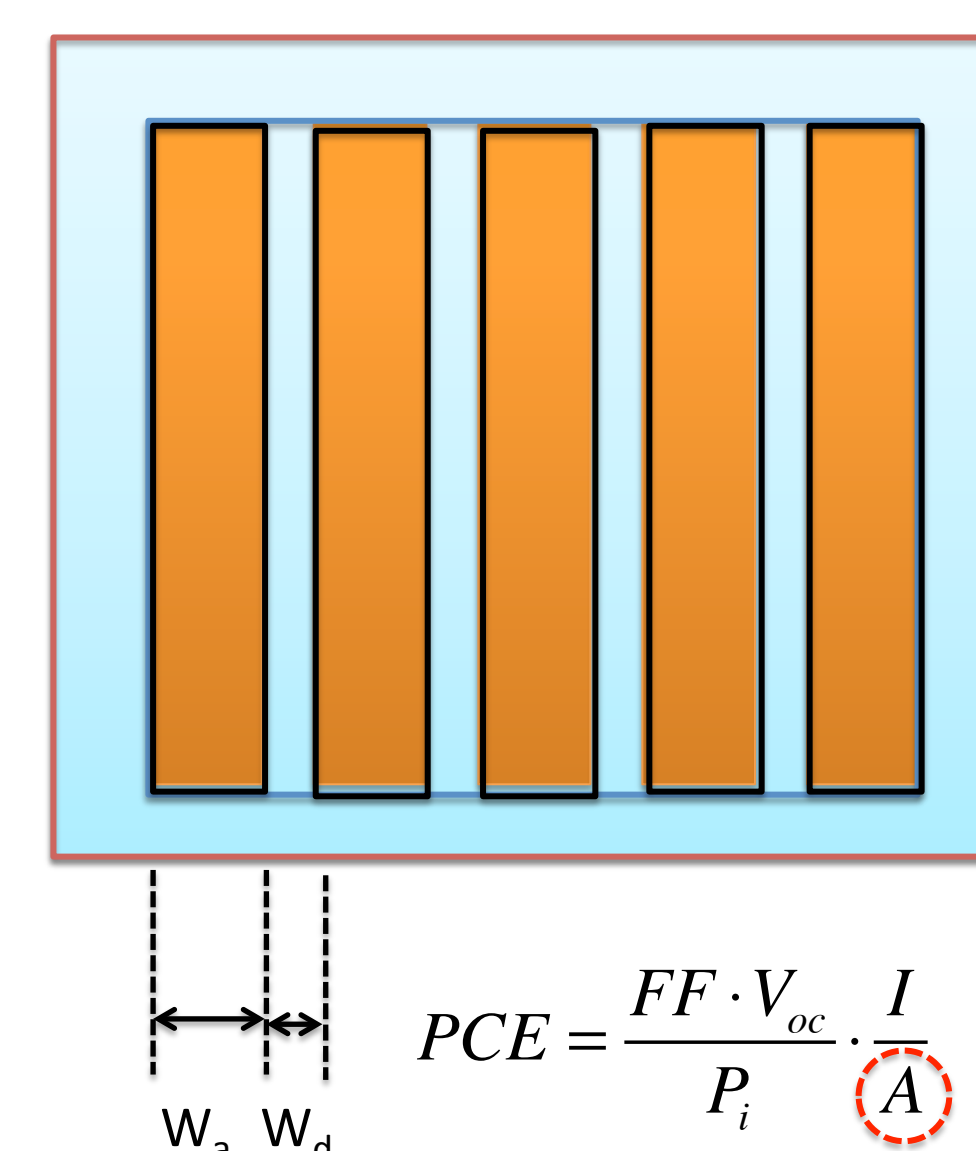


NREL Research Cell Efficiency Records 2015
http://www.nrel.gov/ncpv/images/efficiency_chart.jpg



Perovskite structure (H. S. Kim et al., J. Phys. Chem. C, 2014, 118, 5615)

Module performance characterization



$$f_d = \frac{W_d}{W_a + W_d}$$

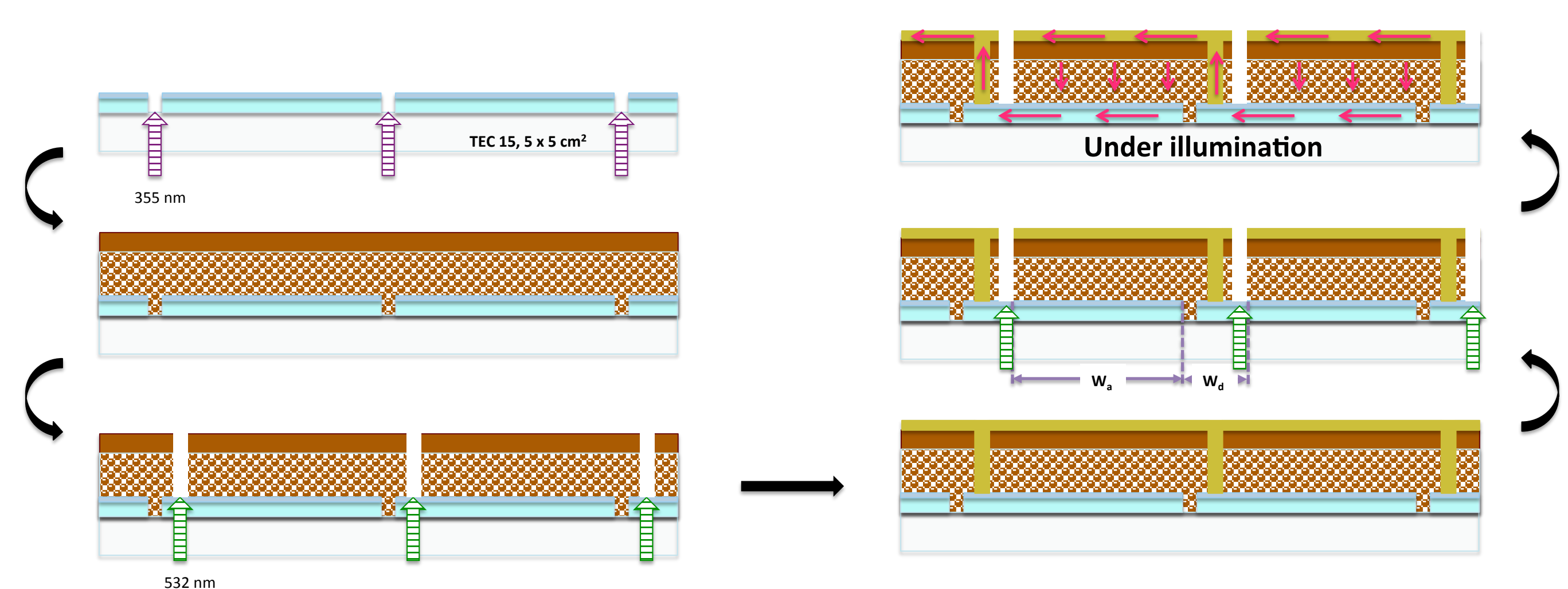
$$f_{TCO} = \frac{1}{3} \cdot R_{sh} \cdot \frac{J_{mpp}}{V_{mpp}} \cdot \frac{W_a^3}{W_a + W_d} \quad (a)$$

Assumption^(b)
J_{sc} = 19.6 mA/cm²
V_{oc} = 1.1 V
FF = 0.74
R_{sh} = 15 Ω/□

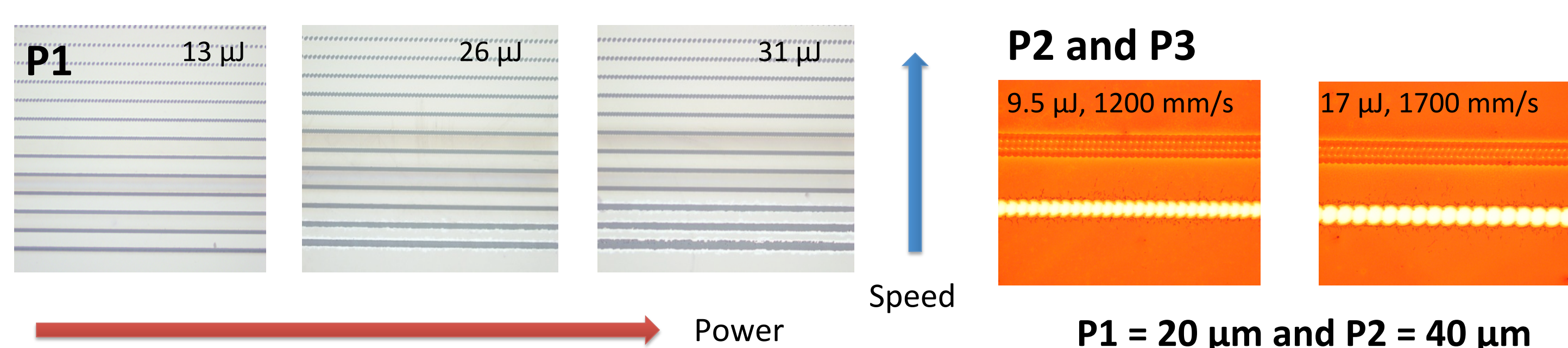
The relative power losses of the module (*f*) depend on the trade-off between the dead area loss (*f_d*) and the TCO resistive loss (*f_{TCO}*)

^(a) S. Haas et al., Prog. Photovolt., 2008, 16, 195–203.
^(b) N. J. Jeon et al., Nat. Mater., 2014, 13, 897–903.

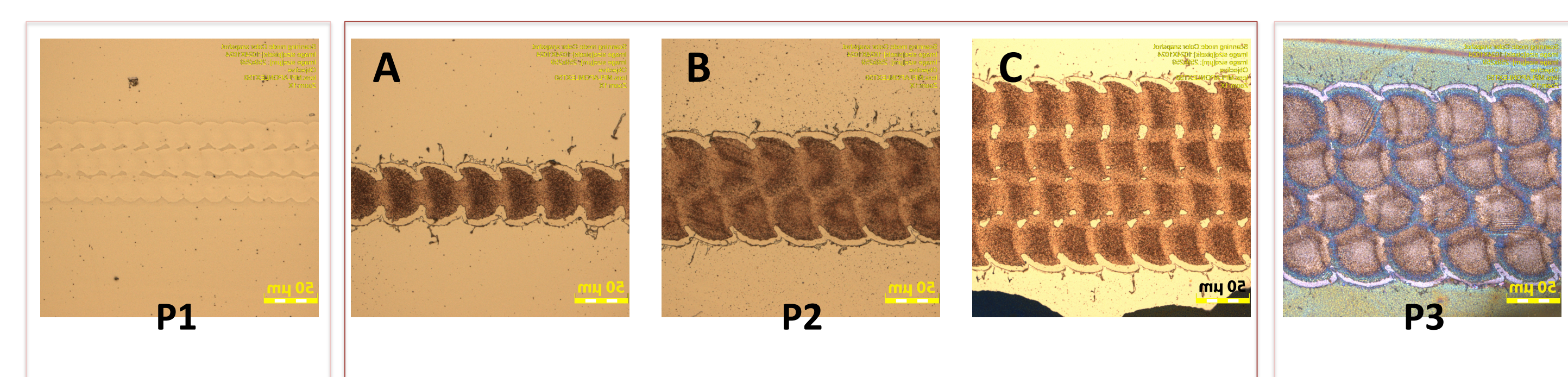
Laser scribing patterning



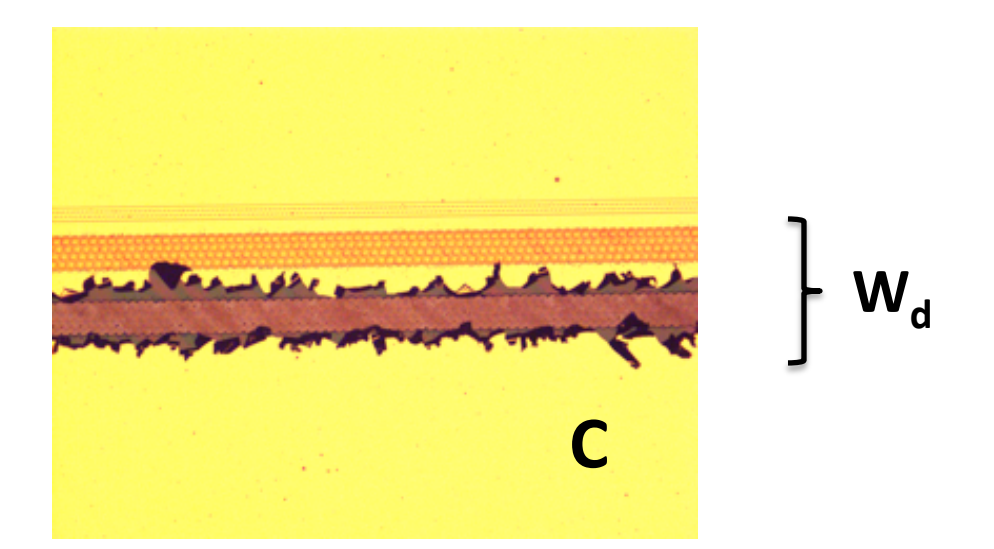
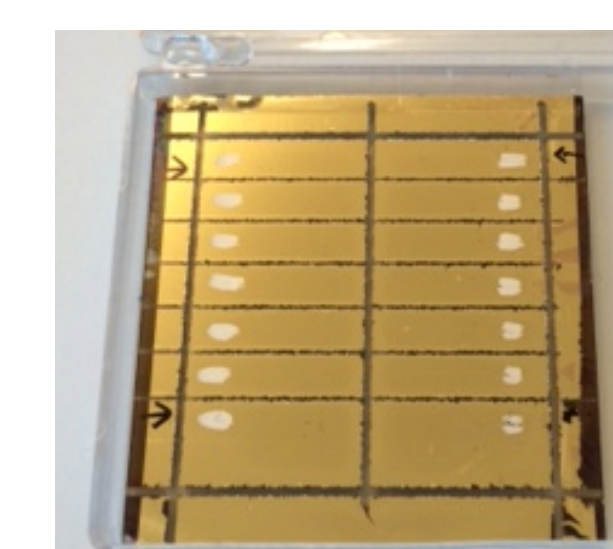
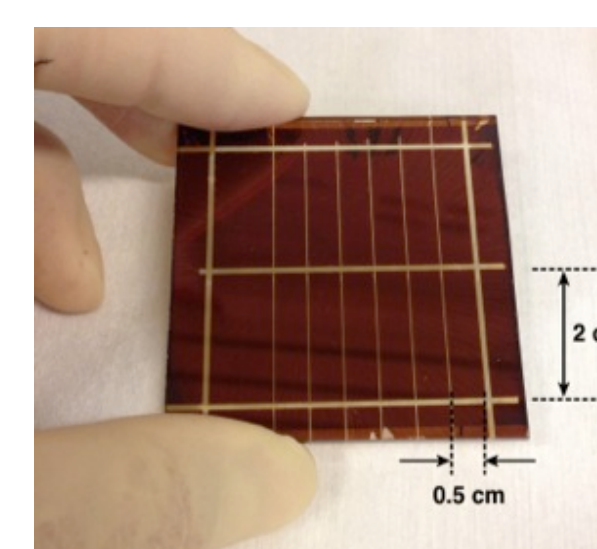
Pattern optimization by laser pulse energy, scribe speed



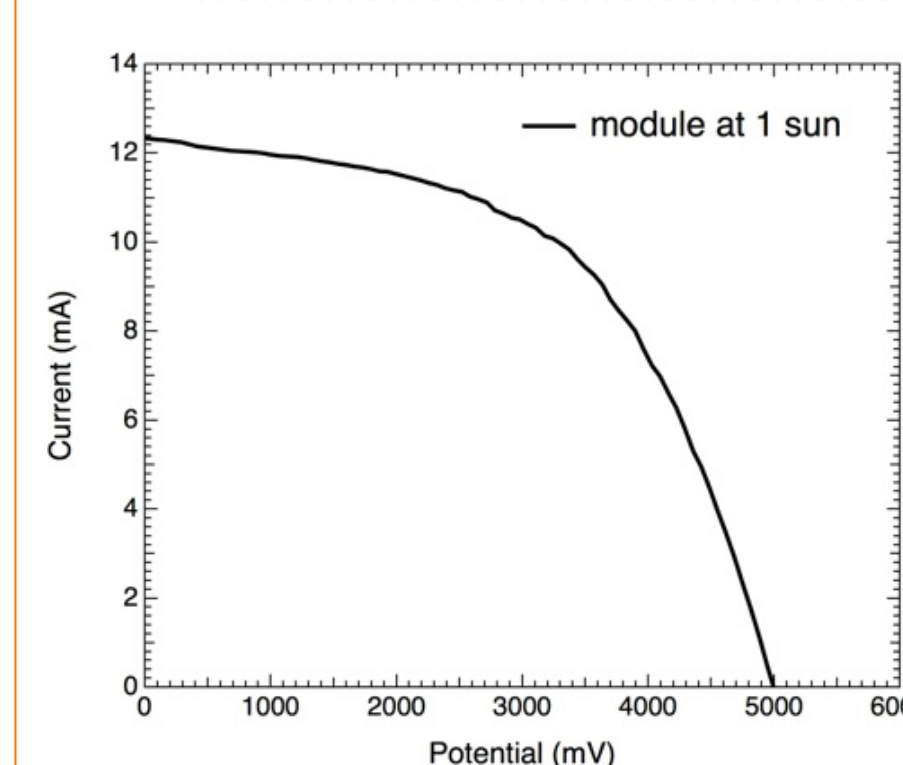
P2 pattern optimization by scribing lines



Results

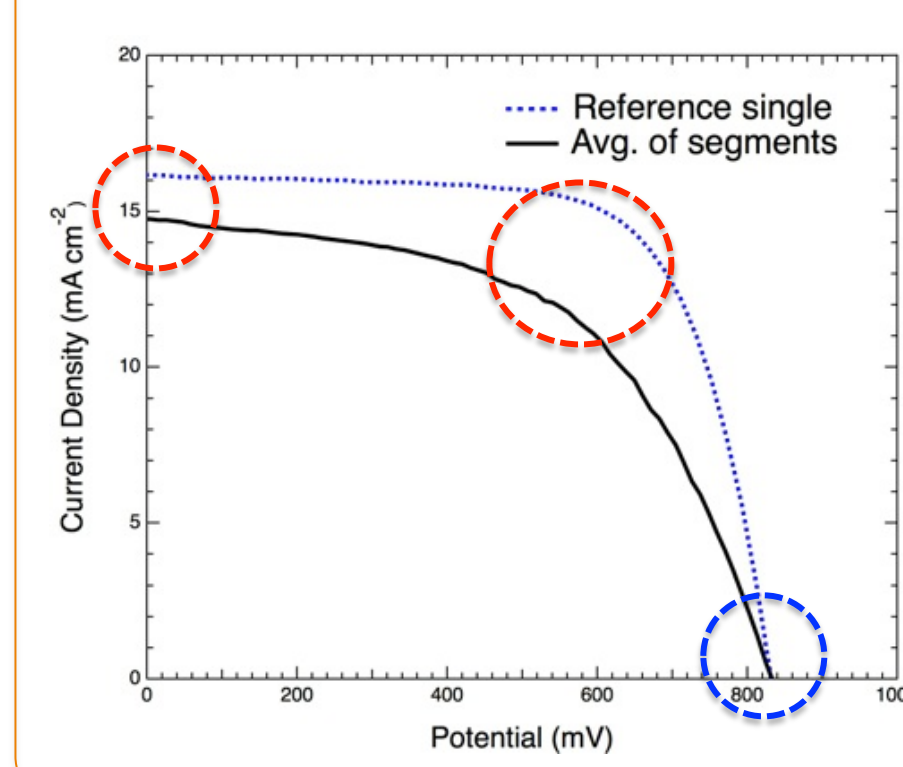


Module	No of P2 lines	W _d (μm)	A _{seg} (cm ²)	F _d (%)
Module A	1	710	0.858	14
Module B	2	750	0.850	15
Module C	4	820	0.836	16



Module	PCE (%)	V _{oc} (mV)/seg	J _{sc} (mA/cm ²)/seg	FF (%)
A	3.60	767	14.2	33.2
B	4.89	785	14.3	43.6
C	6.42	839	14.5	52.9
C	6.60	833	14.8	53.7

Wide P2 improved FF!



Sample	Area (cm ²)	PCE (%)	V _{oc} (mV)	I _{sc} (mA)	J _{sc} (mA/cm ²)	FF (%)
C	5.02	6.60	5000	12.4	14.8	53.7
6.00	5.52					
Segments _{avg}	0.84	6.60	833	12.4	14.8	53.7
Ref	0.43	9.38	842	7.10	16.5	67.7

No loss in V_{oc}!

Summary

1. **Perovskite minimodule**: 5 x 5 cm² mini-module prepared by 1 step perovskite solution process and laser patterning.
2. **< 16 % dead area**: Laser process can achieve dead width smaller than 820 μm.
3. **V_{oc}**: No loss compared to the reference solar cell.
4. **Efficiency**: 6.6 % based on active area and 5.5 % based on aperture area.
5. **Further work**: P2 process optimization and the dead area to < 300 μm or less that 5 % of the active area of the segment.

